L Number	Hits	Search Text	DB	Time stamp
1	68	semiconductor and (insulat$ adj gate) and trench and spacer and source and drain and conduct$ and (pillar or column)	USPAT	2004/07/09 09:59
2	44	semiconductor and (insulat$ adj gate) and trench and spacer and source and drain and conduct$ and (pillar or column)	US-PGPUB	2004/07/09 10:00
3	0	semiconductor and (insulat$ adj gate) and trench and spacer and source and drain and conduct$ and (pillar or column)	EPO	2004/07/09 10:00
4	0	semiconductor and (insulat$ adj gate) and trench and spacer and source and drain and conduct$ and (pillar or column)	JPO	2004/07/09 10:00
5	0	semiconductor and (insulat$ adj gate) and trench and spacer and source and drain and conduct$ and (pillar or column)	DERWENT	2004/07/09 10:00
6	0	semiconductor and (insulat$ adj gate) and trench and spacer and source and drain and conduct$ and (pillar or column)	IBM_TDB	2004/07/09 10:01
7	0	semiconductor and (insulat$ adj gate) and trench and spacer	IBM_TDB	2004/07/09 10:01
8	9	semiconductor and (insulat$ adj gate) and trench and spacer	DERWENT	2004/07/09 10:01
9	0	semiconductor and (insulat$ adj gate) and trench and spacer	JPO	2004/07/09 10:01
10	0	semiconductor and (insulat$ adj gate) and trench and spacer	EPO	2004/07/09 10:01